

T1035H, T1050H

High temperature 10 A Snubberless™ Triacs

Features

- Medium current Triac
- 150 °C max. T_i turn-off commutation
- Low thermal resistance with clip bonding
- Very high 3 quadrant commutation capability
- Packages are RoHS (2002/95/EC) compliant
- UL certified (ref. file E81734)

Applications

Especially designed to operate in high power density or universal motor applications such as vacuum cleaner and washing machine drum motor, these 10 A Triacs provide a very high switching capability up to junction temperatures of 150 °C.

The heatsink can be reduced, compared to traditional Triacs, according to the high performance at given junction temperatures.

Description

Available in through-hole or surface mount packages, the T1035H and T1050H Triacs series are suitable for general purpose mains power ac switching.

By using an internal ceramic pad, the T10xxH-6l provides voltage insulation (rated at 2500 V rms).

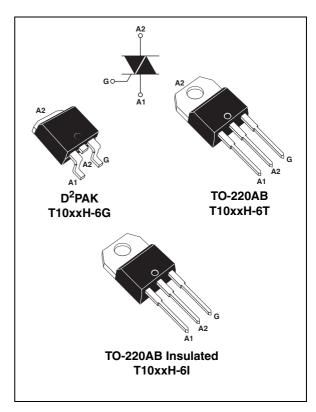


Table 1. Device summary

Symbol	Value	Unit
I _{T(RMS)}	10	Α
V_{DRM}/V_{RRM}	600	V
I _{GT}	35 or 50	mA

TM: Snubberless is a trademark of STMicroelectronics

Characteristics T1035H, T1050H

1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parame	Value	Unit			
	On-state rms current (full sine wave)	D ² PAK, TO-220AB $T_c = 135 ^{\circ}\text{C}$		10	Α	
I _{T(RMS)}		TO-220AB Ins	T _c = 125 °C	10	A	
	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	100	٨	
I _{TSM}	current (full cycle, T _j initial = 25 °C)	F = 60 Hz	t = 16.7 ms	105	Α	
l ² t	I ² t Value for fusing	t _p = 10 ms		66	A ² s	
dI/dt	Critical rate of rise of on-state current I_G = 2 x I_{GT} , $t_r \le 100$ ns	F = 120 Hz	T _j = 150 °C	50	A/μs	
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage $t_p = 10 \text{ ms} \qquad \qquad T_j = 25 \text{ °C}$		V _{DRM} /V _{RRM} + 100	V		
I _{GM}	Peak gate current $t_p = 20 \ \mu s$ $T_j = 150 \ ^{\circ}C$		4	Α		
P _{G(AV)}	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$			1	W	
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C	

Table 3. Electrical characteristics ($T_j = 25$ °C, unless otherwise specified)

Cymbol	Test Conditions	Quadrant		Value		Unit
Symbol	rest Conditions	Quaurant		T1035H	T1050H	Offic
I _{GT} ⁽¹⁾	$V_{\rm D} = 12 \text{ V}, R_{\rm L} = 33 \Omega$	1 - 11 - 111	MAX.	35	50	mA
V_{GT}	VD = 12 V, 11L = 33 32	1 - 11 - 111	MAX.	1.0		V
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ I - II - III		MIN.	0.15		V
I _H ⁽²⁾	I _T = 500 mA	·	MAX.	35	75	mA
IL	I _G = 1.2 I _{GT}	1 - 111	MAX.	50	90	mA
'L	IG - 1.2 IGT	II		80	110	111/2
dV/dt (2)	$V_D = 67\% V_{DRM,}$ gate open, $T_j = 150 ^{\circ}\text{C}$		MIN.	1000	1500	V/µs
(dl/dt)c (2)	Without snubber, T _j = 150 °C		MIN.	13	18	A/ms

^{1.} minimum $I_{\mbox{\footnotesize GT}}$ is guaranted at 20% of $I_{\mbox{\footnotesize GT}}$ max.

^{2.} for both polarities of A2 referenced to A1.

T1035H, T1050H Characteristics

Table 4. Static characteristics

Symbol	Test Conditions			Value	Unit
V _T ⁽¹⁾	I _{TM} = 14 A, t _p = 380 μs	T _j = 25 °C	MAX.	1.5	V
V _{t0} ⁽¹⁾	Threshold voltage	T _j = 150 °C	MAX.	0.80	V
R _d ⁽¹⁾	Dynamic resistance	T _j = 150 °C	MAX.	34	$m\Omega$
	V - V	T _j = 25 °C	MAX.	5	μΑ
I _{DRM}	$V_{DRM} = V_{RRM}$	T _j = 150 °C	MAX.	3.6	
I _{RRM} ⁽²⁾	V _D /V _R = 400 V (at peak mains voltage)	T _j = 150 °C	MAX.	3.0	mA
	V _D /V _R = 200 V (at peak mains voltage)	T _j = 150 °C	MAX.	2.5	

^{1.} for both polarities of A2 referenced to A1.

Table 5. Thermal resistance

Symbol	Parameter			Value	Unit
R _{th(j-c)} Junction to case (AC)			D ² PAK / TO-220AB	1.45	
			TO-220AB Ins	3.4	°C/W
R _{th(j-a)} Junction to ambient	lunction to ambient	$S = 1 \text{ cm}^2$	D ² PAK	45	C/VV
	Junction to ambient		TO-220AB / TO-220AB Ins	60	

^{2.} $t_p = 380 \mu s$

Characteristics T1035H, T1050H

Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case on-state rms current (full cycle) temperature (full cycle)

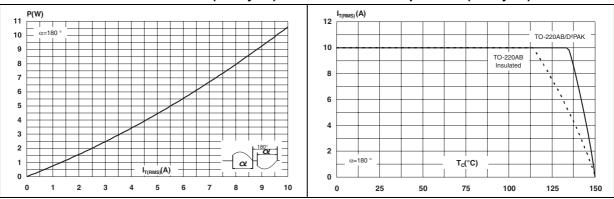


Figure 3. On-state rms current versus ambient temperature

Figure 4. Variation of thermal impedance versus pulse duration

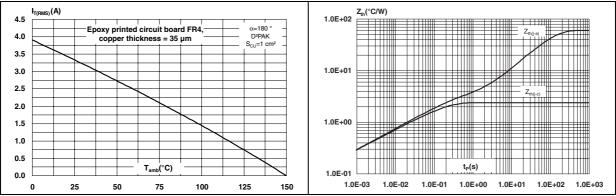
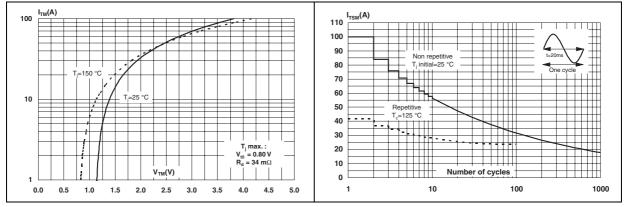


Figure 5. On-state characteristics (maximum values)

Figure 6. Surge peak on-state current versus number of cycles



4/10 Doc ID 13565 Rev 2

T1035H, T1050H Characteristics

Figure 7. Non-repetitive surge peak on-state Figure 8. Relative variation of I_{GT} , I_{L} vs current for a sinusoidal pulse with junction temperature (typical values)

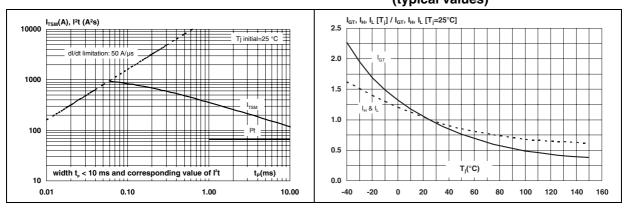


Figure 9. Relative variation of critical rate of decrease of main current (dl/dt)c versus reapplied (dV/dt)c

Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature

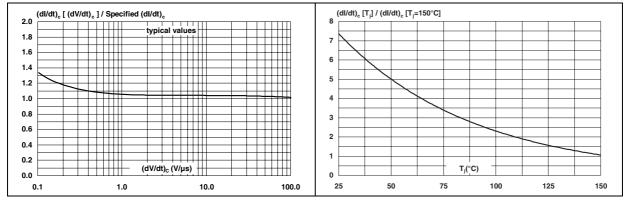
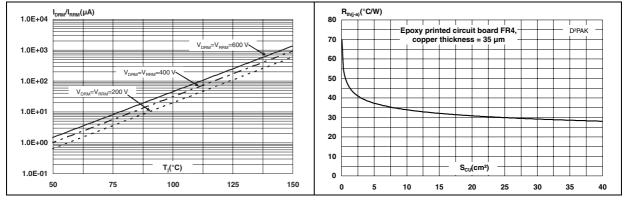


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

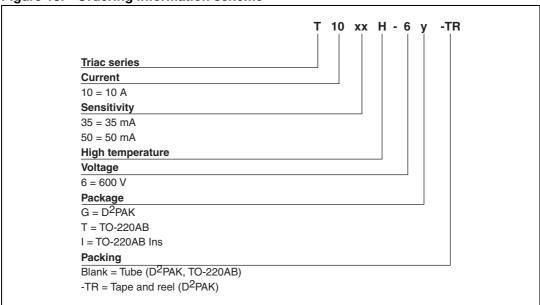
Figure 12. Variation of thermal resistance junction to ambient versus copper surface under tab



6/10

2 Ordering information scheme

Figure 13. Ordering information scheme



T1035H, T1050H Package information

3 Package information

- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 6. D²PAK dimensions

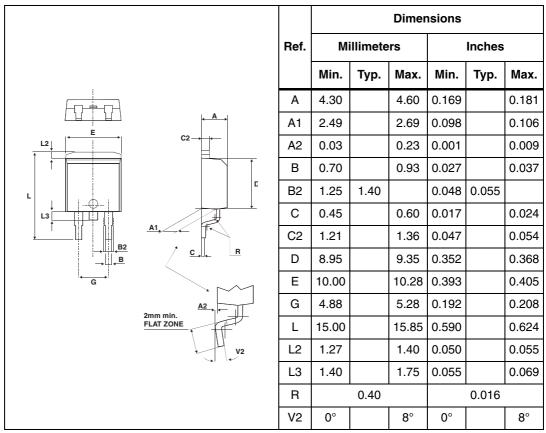
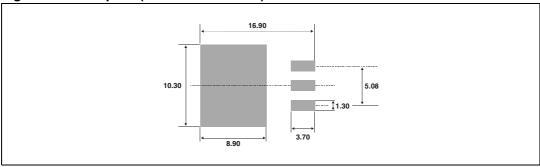


Figure 14. Footprint (dimensions in mm)



Package information T1035H, T1050H

Dimensions Ref. Millimeters Inches Min. Typ. Max. Min. Тур. Max. 15.20 15.90 0.598 0.625 Α 0.147 a1 3.75 В a2 13.00 14.00 0.511 0.551 Ø١ В 10.00 10.40 0.393 0.409 b1 0.61 0.88 0.024 0.034 0.051 b2 1.23 1.32 0.048 14 С 4.40 4.60 0.173 0.181 13 с1 0.49 0.70 0.019 0.027 c2 c2 2.40 2.72 0.094 0.107 a2 2.40 2.70 0.094 0.106 е F 6.20 6.60 0.244 0.259 ØΙ 3.75 3.85 0.147 0.151 0.661 14 15.80 16.40 16.80 0.622 0.646 L 2.65 2.95 0.104 0.116 12 1.14 0.044 0.066 1.70 13 1.14 1.70 0.044 0.066 Μ 2.60 0.102

Table 7. TO-220AB and TO-220AB Ins dimensions

8/10

4 Ordering information

 Table 8.
 Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T10xxH-6G	T10xxH 6G	D ² PAK	1.5 g	50	Tube
T10xxH-6G-TR	T10xxH 6G	D ² PAK	1.5 g	1000	Tape and reel
T10xxH-6T	T10xxH 6T	TO-220AB	2.3 g	50	Tube
T10xxH-6I	T10xxH 6l	TO-220AB Ins	2.3 g	50	Tube

5 Revision history

Table 9. Document revision history

Date	Revision	Changes	
17-Apr-2007	1	First issue	
20-Sep-2011	2	Updated: Features, Description and Figure 2.	

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2011 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

10/10 Doc ID 13565 Rev 2

